



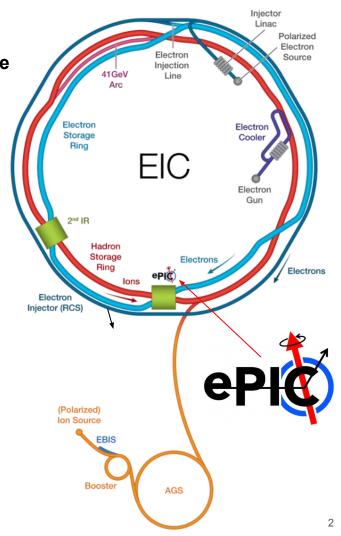
A SiPM-based optical readout for the ePIC dual-radiator RICH

Roberto Preghenella INFN Bologna

The Electron-Ion Collider

a machine that will unlock the secrets of the strongest force in Nature is a future electron-proton and electron-ion collider at BNL (USA) foreseen to start operation in early 2030's

- the major US project in the field of nuclear physics
 - one of the most important scientific facilities for the future of nuclear and subnuclear physics
- the world's first collider for
 - polarised electron-proton (and light ions)
 - o electron-nucleus collisions
- will allow to explore the secrets of QCD
 - understand origin of mass & spin of the nucleons
 - extraordinary 3D images of the nuclear structure

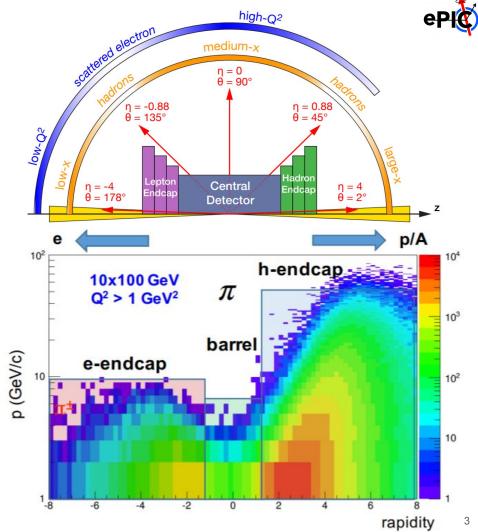


www.bnl.gov/eic

Particle identification at the EIC

one of the major challenges for the detector

- physics requirements
 - o pion, kaon and proton ID
 - ∘ over a wide range $|\eta| \le 3.5$
 - with better than 3σ separation
 - significant pion/electron suppression
- momentum-rapidity coverage
 - o forward: up to 50 GeV/c
 - o central: up to 6 GeV/c
 - o backward: up to 10 GeV/c
- demands different technologies



The ePIC experiment

layout of the barrel detector



8.5 m

tracking

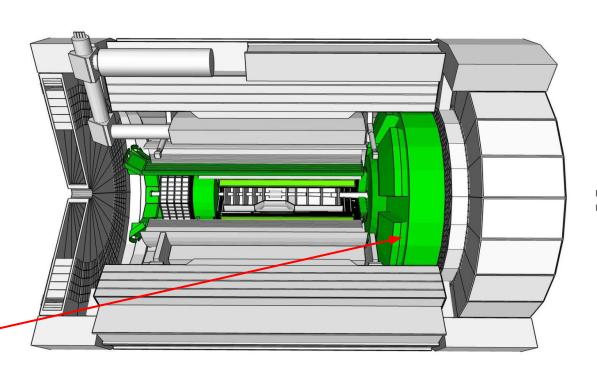
- o new 1.7 T magnet
- Si-MAPS + MPGDs

calorimetry

- o e-side: PbWO₄ EMCal
- o barrel: imaging EMCal
- h-side: finely segmented
- outer barrel HCal

particle ID

- AC-LGAD TOF
- o pfRICH
- o hpDIRC
- o dRICH



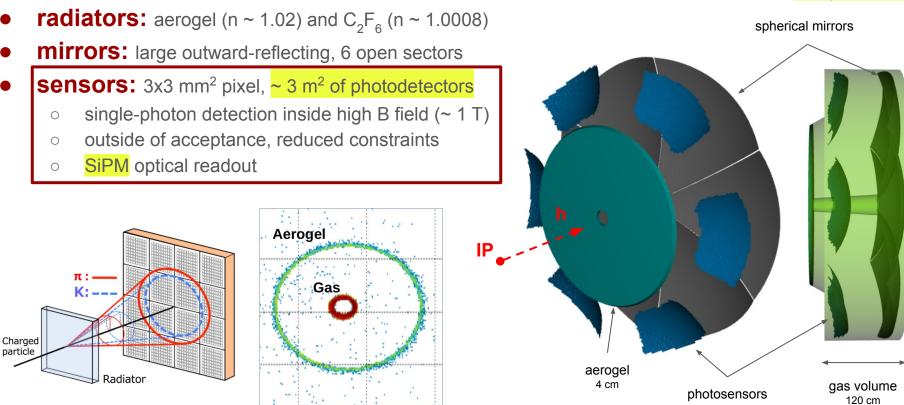
hadrons — electrons

The dual-radiator (dRICH) for forward PID at EIC



compact and cost-effective solution for broad momentum coverage at forward rapidity

p = [3.0, 50] GeV/c η = [1.5, 3.5] e-ID up to 15 GeV/c



SiPM option and requirements for RICH optical readout







- cheap
- high photon efficiency
 requirement
- excellent time resolution
- insensitive to magnetic field
 requirement



large dark count rates not radiation tolerant

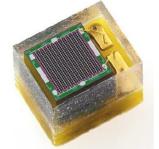
technical solutions and mitigation strategies

cooling
timing

annealing

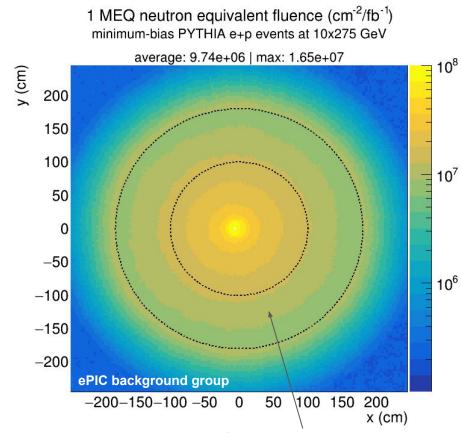






Radiation damage estimates





Most of the key Physics goals defined by the NAS require an integrated luminosity of 10 fb⁻¹ per center of mass energy and polarization setting

The nucleon imaging programme is more luminosity hungry and requires 100 fb⁻¹ per center of mass energy and polarization setting

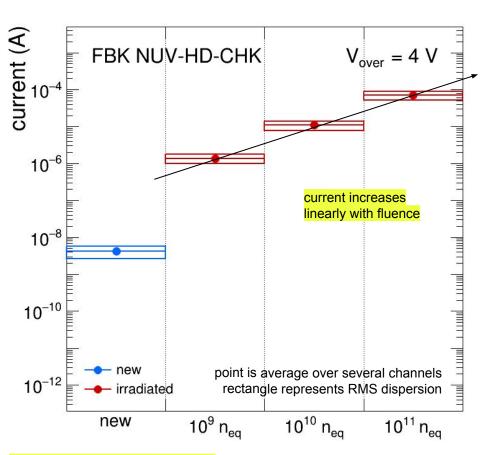
in 10-12 years the EIC will accumulate 1000 fb⁻¹ integrated £ corresponding to an integrated fluence of ~ 10¹⁰ n_{eo}/cm²

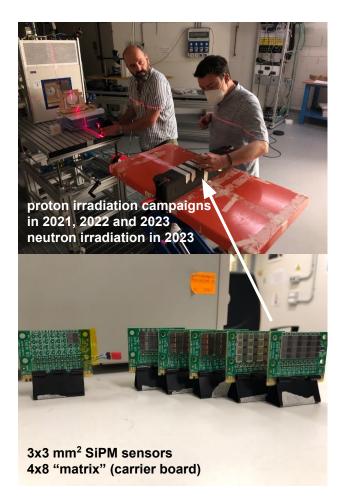
study the SiPM usability for single-photon
Cherenkov imaging applications in
moderate radiation environment

max fluence = $1.75 ext{ } 10^7 ext{ } \text{neq/fb}^{-1}$ at the location of dRICH photosensors

Studies of radiation damage on SiPM

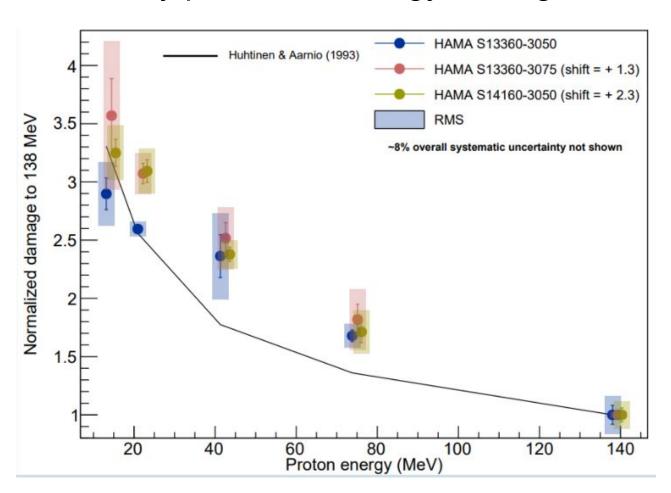






Preliminary proton vs. energy damage





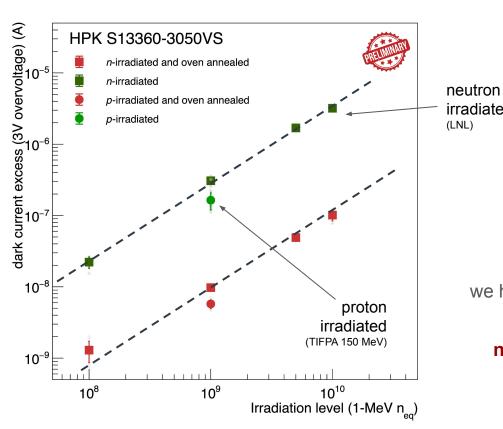
we have very preliminary results on comparison between of proton damage vs. proton energy to NIEL hypothesis which indicate that the scaling is valid within 30-50%

using NIEL scaling for normalisation

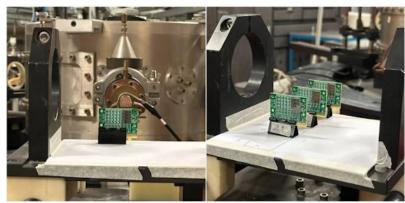
Preliminary comparison of neutron vs. proton damage



neutrons from Be(d,n) reaction with 4 MeV deuteron beam



irradiated



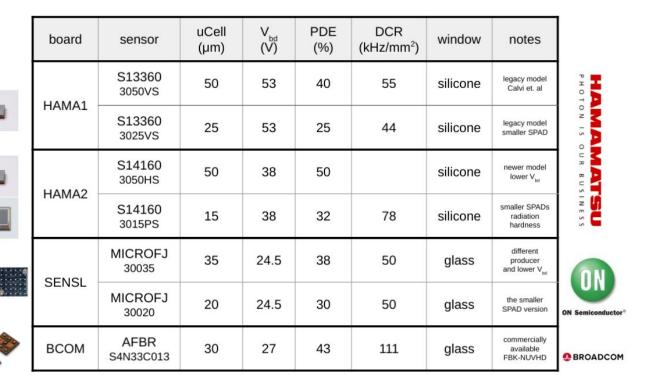
we have very preliminary results on comparison between neutron and proton damage which indicate that

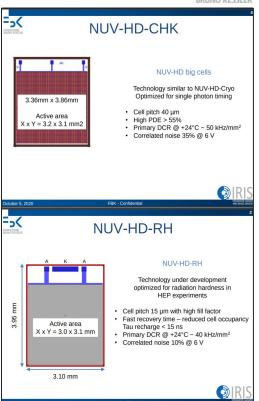
neutron damage is larger after same n_{eq} fluence using NIEL scaling for normalisation

by approximately a factor of 2x we use a 10x safety factor for radiation damage estimates

Commercial SiPM sensors and FBK prototypes



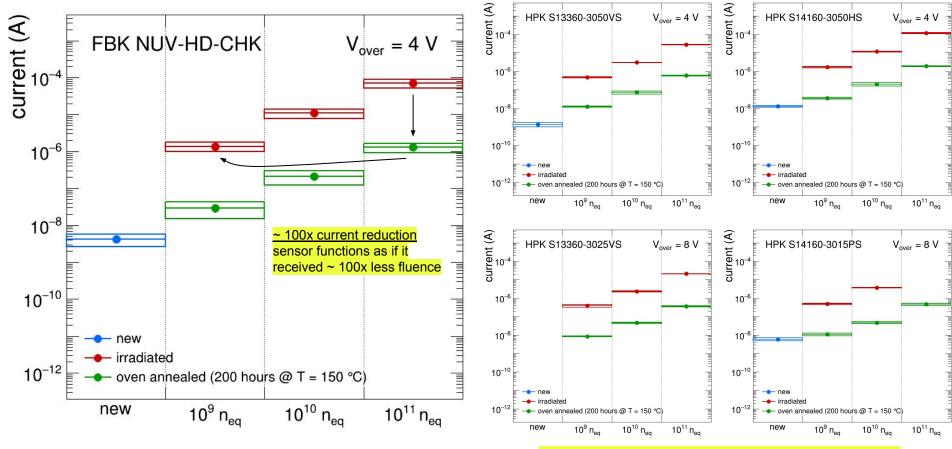




High-temperature annealing recovery

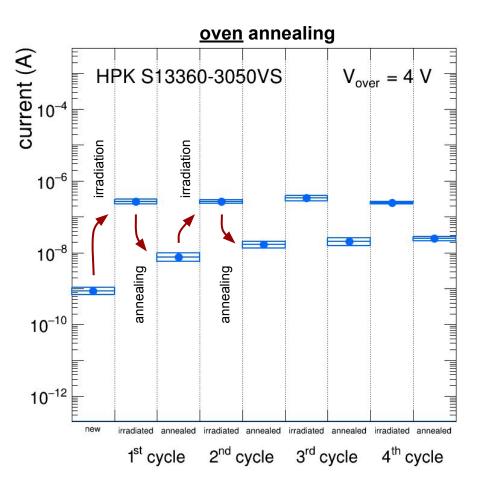
oven annealing ~ 1 week at 150 C





Repeated irradiation-annealing cycles





test reproducibility of repeated irradiation-annealing cycles

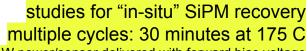
simulate a realistic experimental situation

- consistent irradiation damage
 - ODCR increases by ~ 500 kHz (@ Vover = 4)
 - after each shot of 10⁹ n_{eq}
- consistent residual damage
 - ~ 15 kHz (@ Vover = 4) of residual DCR
 - builds up after each irradiation-annealing

annealing cures same fraction of newly-produced damage

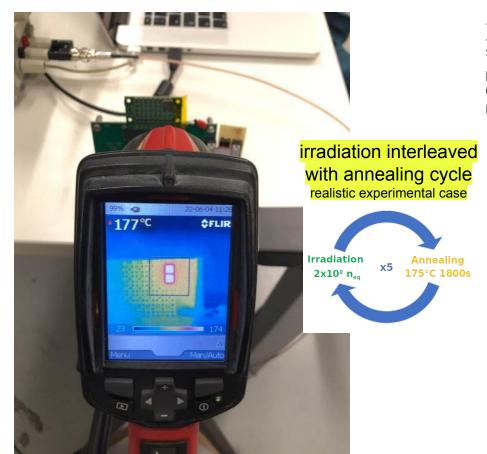
~ 97% for HPK S13360-3050 sensors

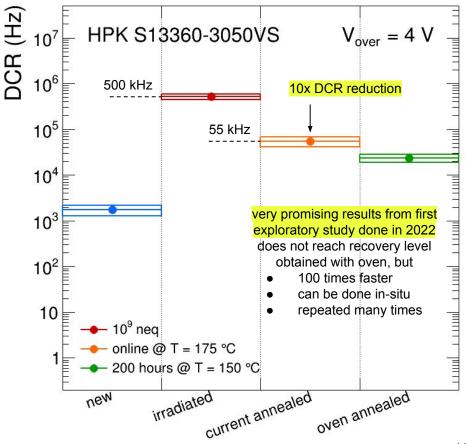
"Online" self-induced annealing





~ 1 W power/sensor delivered with forward bias voltage





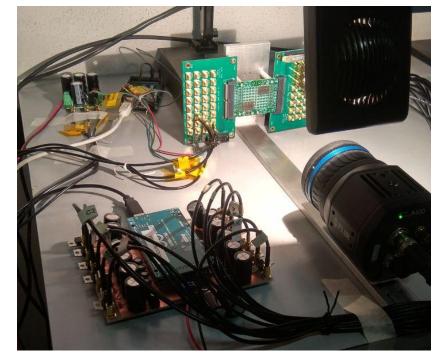
Automated multiple SiPM online self-annealing



thermal camera SiPM sensors & control electronics thermal image monitor and logging system **175** ℃ 150 -200 -

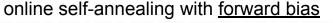
system for online self-annealing with temperature

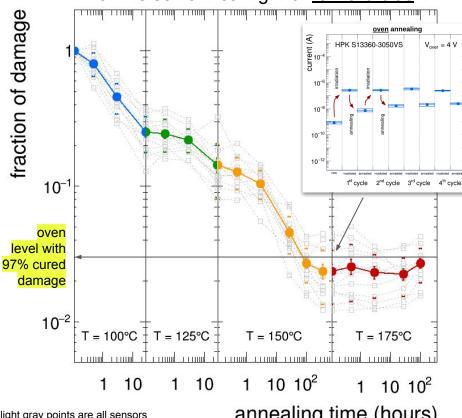
monitor and control of each individual SiPM



Detailed studies of SiPM online self-annealing







light gray points are all sensors coloured points are averaged over sensors coloured brackets is the RMS

annealing time (hours)

test on a large number SiPM sensors how much damage is cured as a function of temperature and time

the same sensors have undergone self-annealing increasing temperature steps increasing integrated time steps

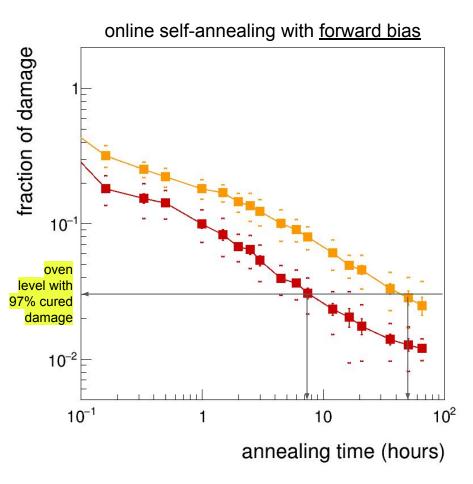
- started with T = 100 C annealing
 - o performed 4 steps up to 30 hours integrated
- followed by T = 125, 150 and 175 C

fraction of residual damage seems to saturate at 2-3% after ~ 300 hours at T = 150 C

continuing at higher T = 175 C seems not to cure more than that

Automated multiple SiPM online self-annealing





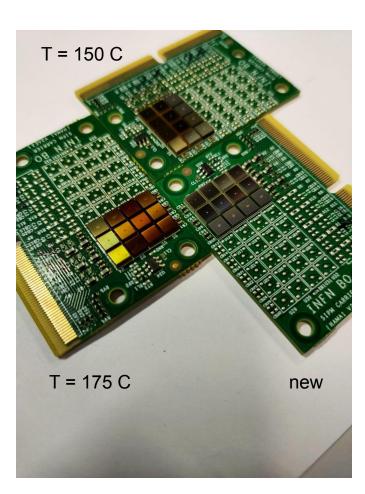
comparison between two annealing temperatures

both reach and exceed the oven limit of ~ 2-3% residual damage

- at T = 175 C
 - there seems to be a faster "sudden" cure
 - followed by a similar rate of reduction with time
- oven-level annealing reached faster at T = 175 C
 - < 10 hours integrated</p>
- oven-level annealing reached at T = 150 C
 - < 100 hours integrated</p>

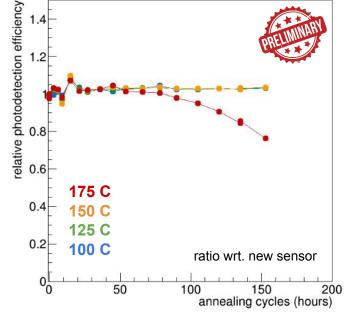
Detailed studies of SiPM online self-annealing





after many hours of online annealing

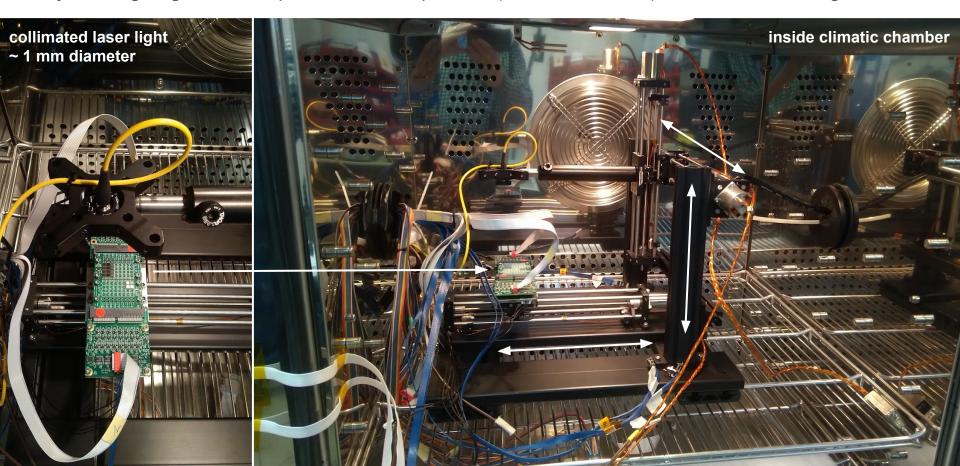
we noticed alterations on the SiPM windows in particular in one board that underwent 500 hours of online annealing at T = 175 C the sensors appear "yellowish" when compared to new



detailed studies are ongoing, preliminary results indicate efficiency loss after 100 hours of annealing at T = 175 C. lower temperatures unaffected up to 150 hours

Upgraded laser setup at INFN Bologna

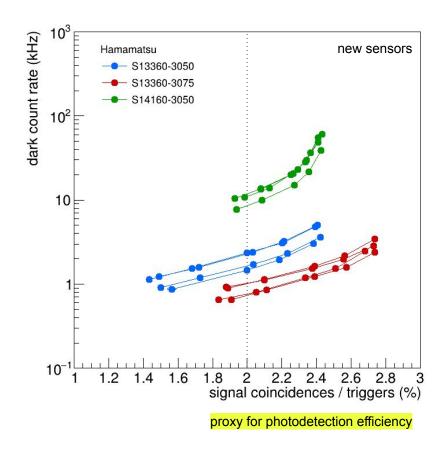
new xyz moving stage that can operate at low temperature (down to T = -40 C) within a 200 mm range



DCR vs. PDE comparison between sensors



3 Hamamatsu sensor types, 4 sensors each measured as NEW



at the same level of detection efficiency namely, the probability to detect light from laser pulse different sensors have different DCR level

best: S13360-3075

most promising sensors, large pitch SPADs (75 μ m)

second: S13360-3050

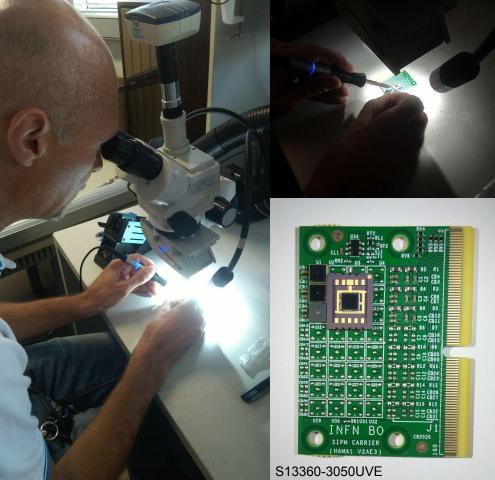
same technology, medium pitch SPADs (50 μm)

worst: S14160-3050

different technology, medium pitch SPADs (50 µm)

New Hamamatsu SiPM prototypes





newly-developed Hamamatsu SiPM sensors

based on S13360 series

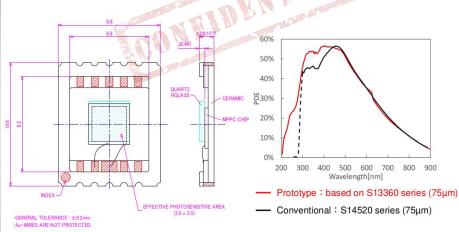
few samples of 50 μm and 75 μm SPAD sensors

on paper they look VERY promising

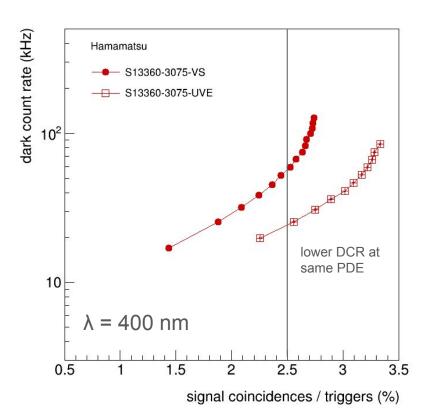
- improved NUV sensitivity
- improved signal shape
- improved recharge time

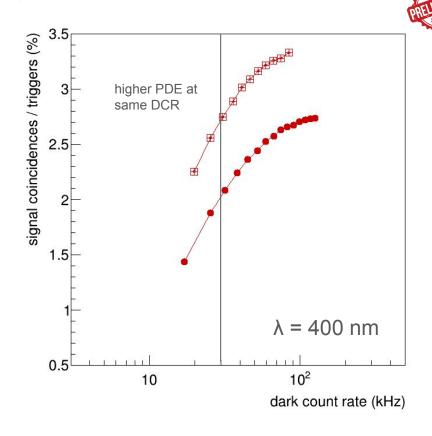
mounted on EIC SiPM test boards we will characterise and test them in full

irradiation, annealing, laser, ...



prototype Hamamatsu sensors (10⁹ neq after oven annealing)





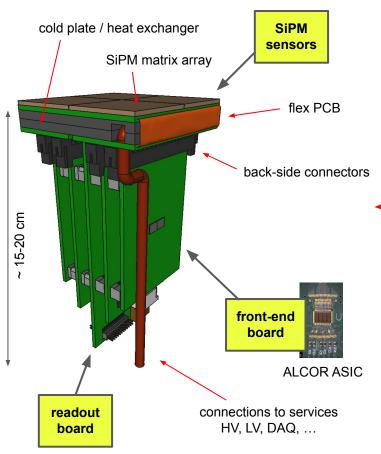
prototype Hamamatsu UVE sensors have significantly higher efficiency than standard sensors caveat: we only measure PDE at the fixed laser wavelength of ~400 nm, larger PDE expected because... prototype sensors have a NUV-enhanced behaviour.

we will study them further, currently asking Hamamatsu status for production and quotation of this product

detector integration and electronics

Photodetector unit

conceptual design of PDU layout

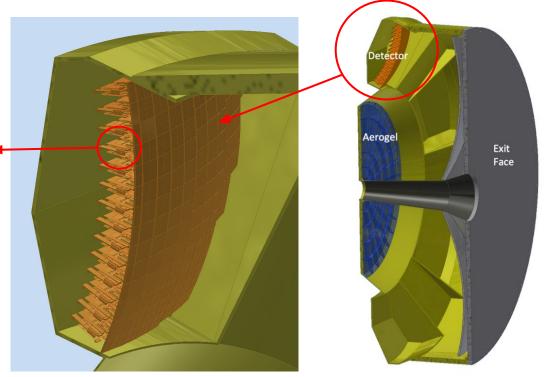


SiPM sensor matrices mounted on carrier PCB board



need modularity to realise curved readout surface

- 1248 photodetector units for full dRICH readout
 - 4992 SiPM matrix arrays (8x8)
 - o 319488 readout channels



24

ALCOR ASIC: integrated front-end and TDC





developed by INFN-TO

64-pixel matrix mixed-signal ASIC current versions (v1,v2,v2.1) have 32 channels, wirebonded final version will have 64 channels, BGA package, 394.08 MHz clock

the chip performs

- signal <u>amplification</u>
- conditioning and event <u>digitisation</u>

each pixel features

- 2 leading-edge discriminators
- 4 TDCs based on analogue interpolation
 - 20 or 40 ps LSB (@ 394 MHz)
- digital shutter to enable TDC digitisation
 - suppress out-of-gate DCR hits
 - 1-2 ns timing window
 - programmable delay, sub ns accuracy

single-photon time-tagging mode

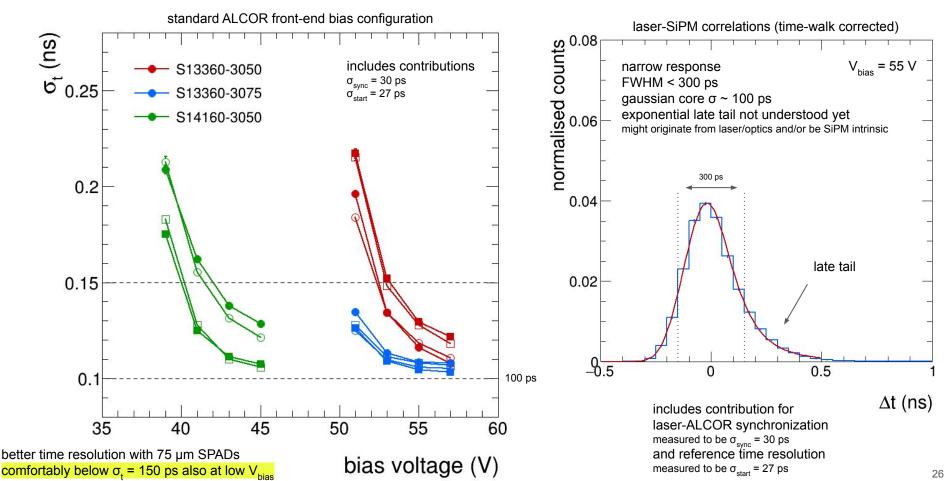
- o continuous readout
- o also with Time-Over-Threshold

fully digital output

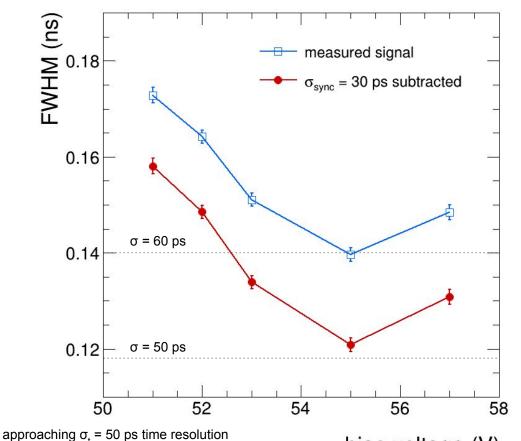
8 LVDS TX data links

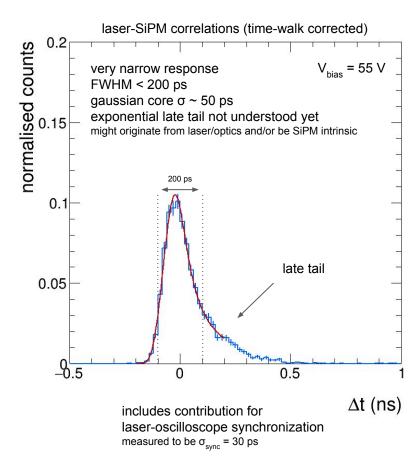
Timing performance measurements with ALCOR



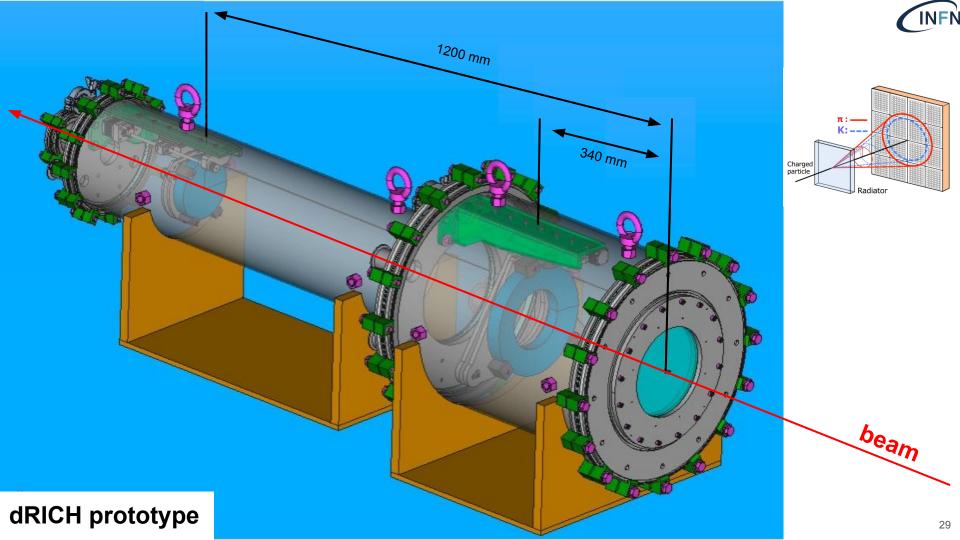


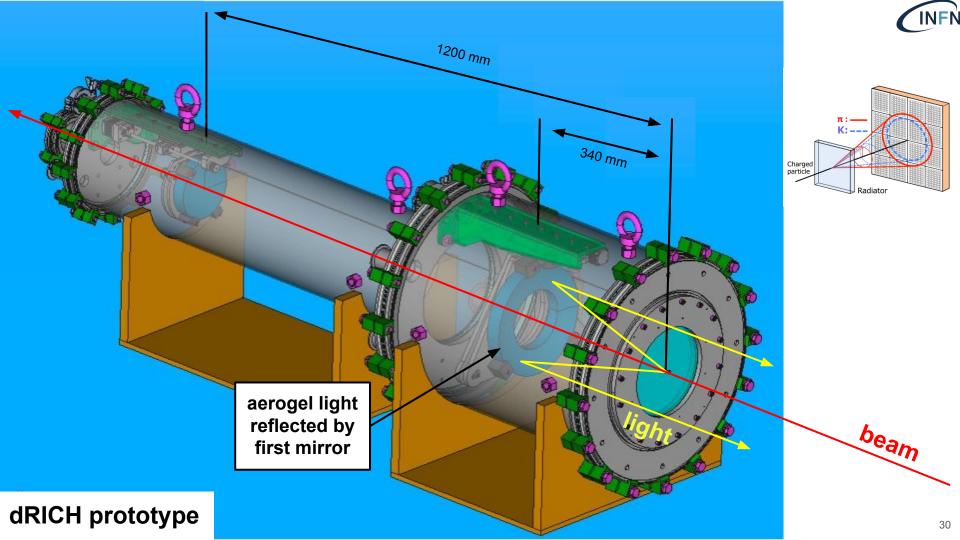
Laser timing measurements with oscilloscope

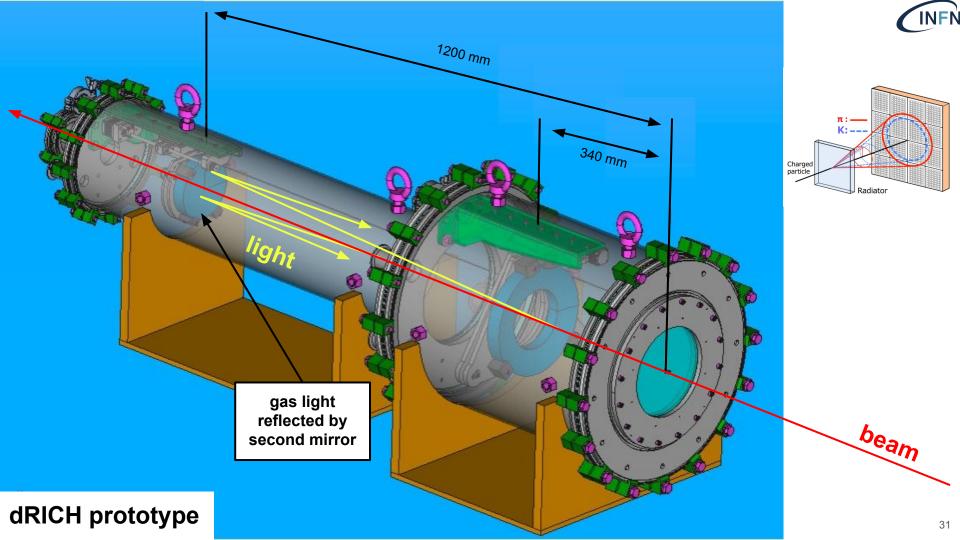


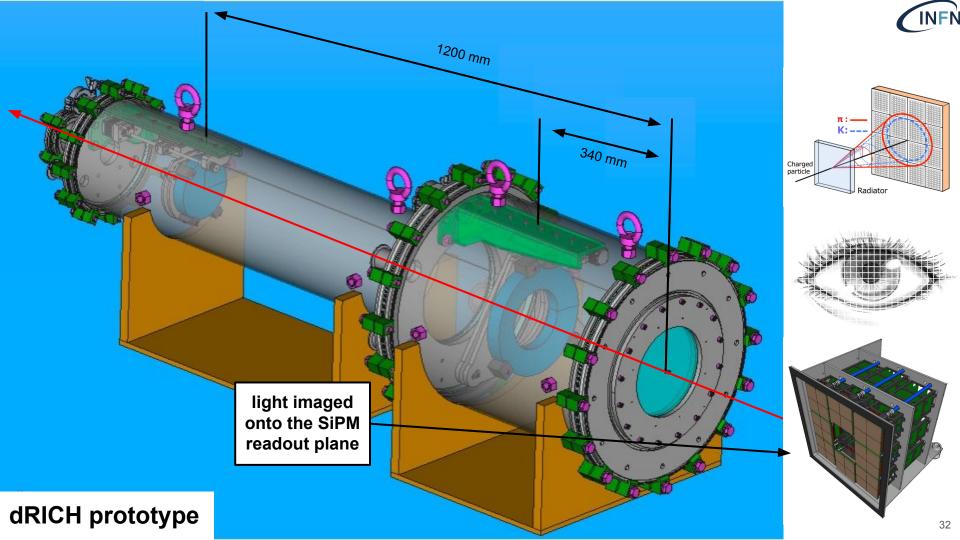


detector prototype and beam tests



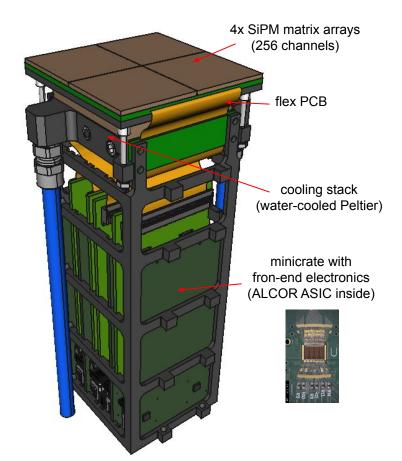


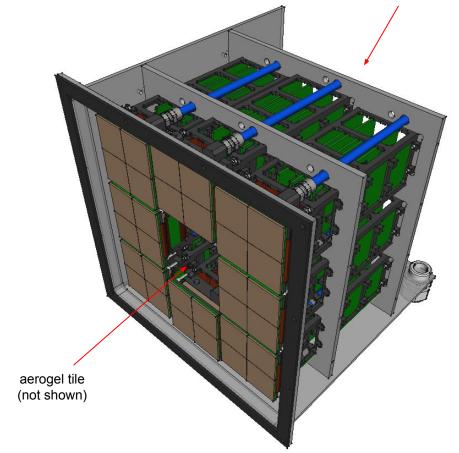




EIC ePIC-dRICH SiPM photodetector prototype

cables and services (not shown)



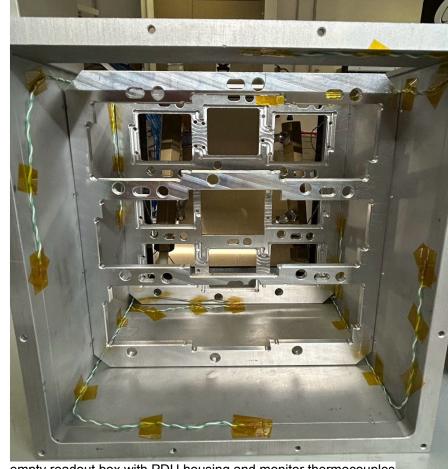


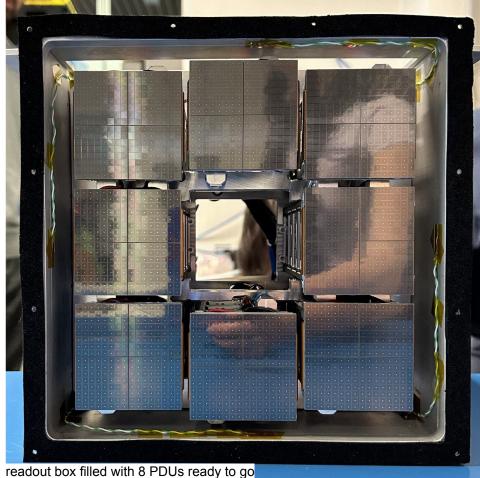
PhotoDetector Unit (PDU)

Readout Box

From an empty box to a full detector





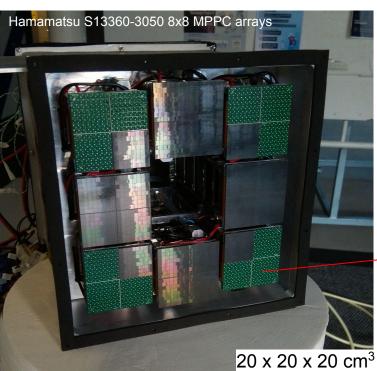


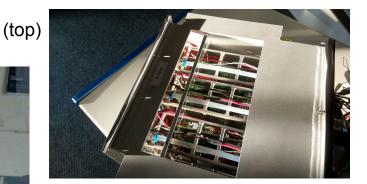
empty readout box with PDU housing and monitor thermocouples

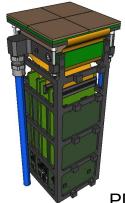
dRICH SiPM photodetector prototype in 2023



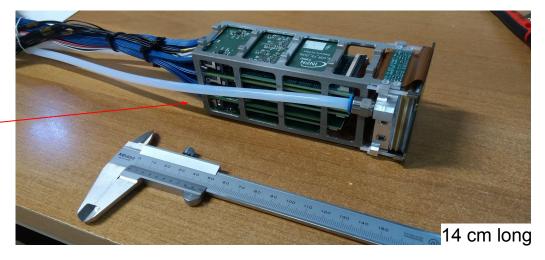
Readout Box (front)







PDU

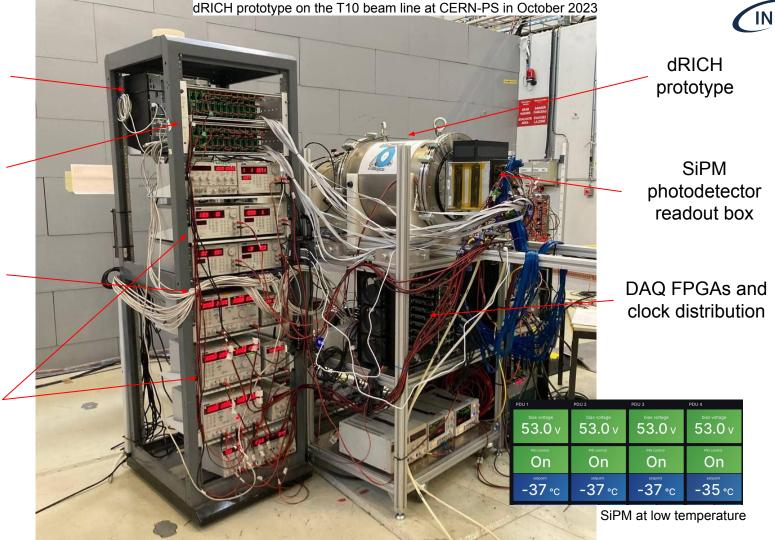


DAQ and DCS computers

auxiliary control electronics crates

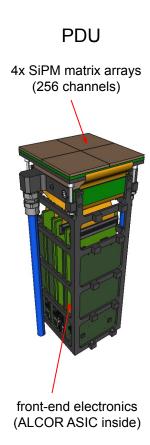
gigabit ETH switch for DAQ and DCS

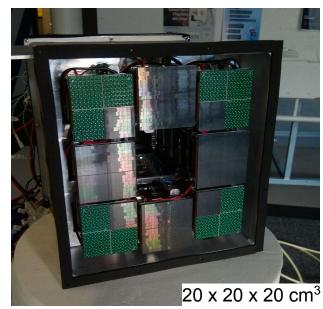
low voltage and high voltage power supplies



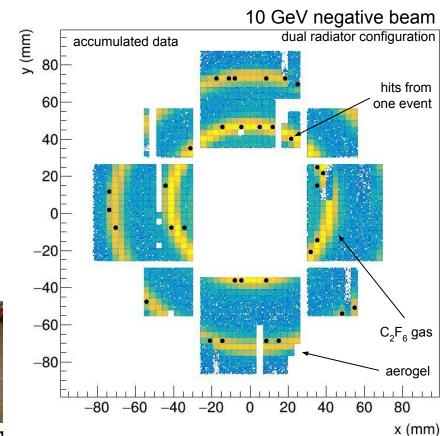


successful beam test with prototype SiPM photodetector units (CERN-PS, ended on 18th October)





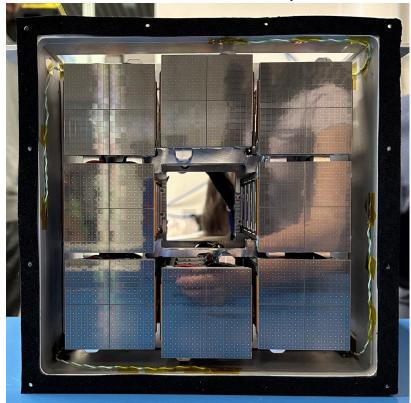




Upgraded in 2024 with 2k channels



Hamamatsu S13360-3050/3075 8x8 MPPC arrays



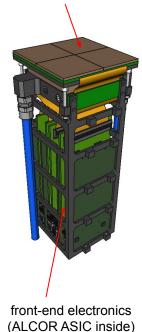


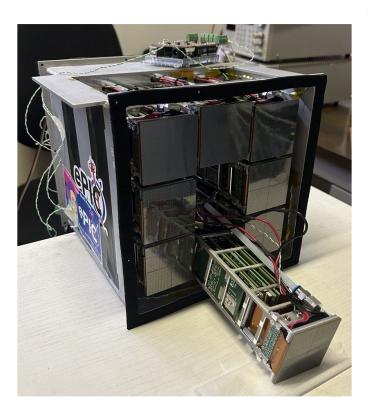


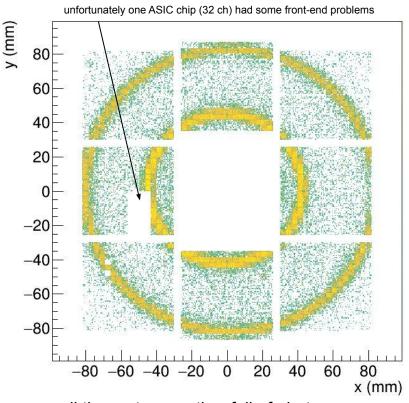
another successful beam test with prototype SiPM photodetector units (CERN-PS, ended on 5th June)

PDU

4x SiPM matrix arrays (256 channels)







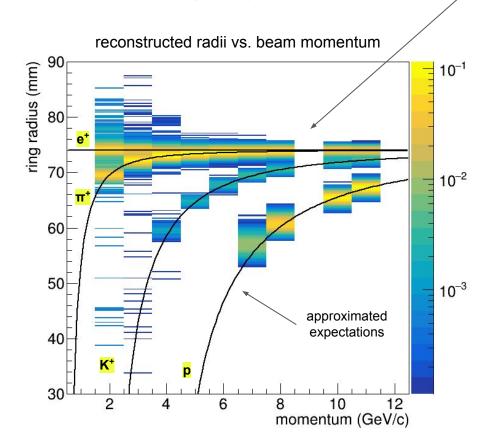
all the rest was rather full of photons

> 2000 SiPMs with TDC readout at work

Beam momentum scan

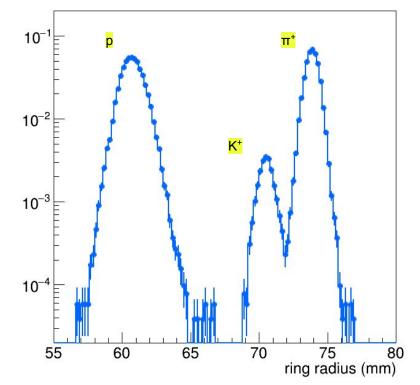


positive particles, aerogel only



something went wrong with the beam configuration for 9 GeV (that's a pity, data seems not good)

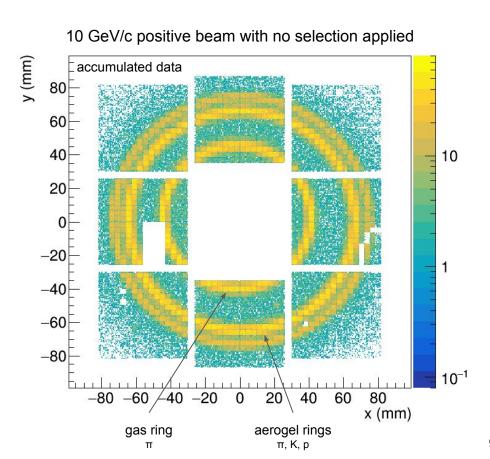
reconstructed ring radius at 8 GeV/c beam momentum



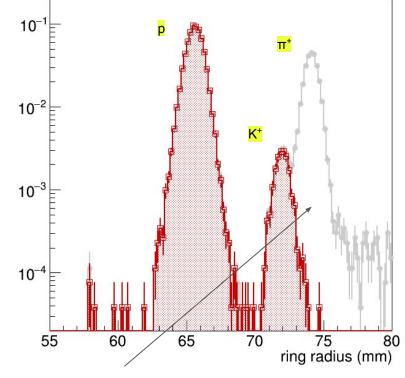
Interplay between aerogel and gas radiators



gas ring tags pions, at 10 GeV/c kaons and protons are below C₂F₆ gas threshold



reconstructed ring radius at 10 GeV/c with gas veto





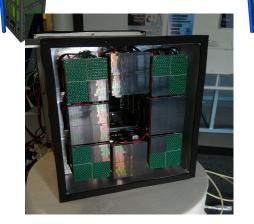


2022

electronics v1



electronics v2



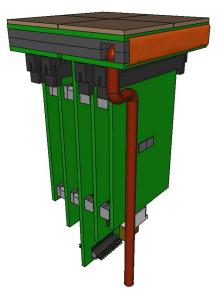
2024

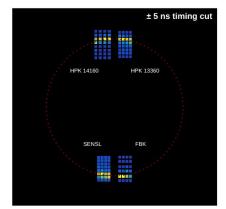
electronics v2.1

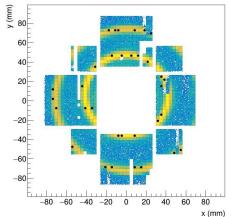


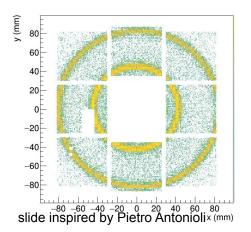
2025

electronics v3 final prototype









Summary



dRICH SiPM option fulfills dRICH requirements

- magnetic field limitations
- excellent timing and efficiency

technical solutions to mitigate radiation damage

- low temperature operation
- online "in-situ" self-annealing
- extend lifetime of good detector performance for Physics
 - present solutions can be optimised/improved to extend it further

SiPM readout with full electronics chain

- based on ALCOR ASIC
- successful beam tests at CERN-PS in 2022, 2023 and 2024
- overall 1-pe time resolution approaching 100 ps
- o ring-imaging, particle-identification and more
- beam test data-analysis ongoing

clear path for optimisation towards TDR and beyond

- refinements, engineering and SiPM sensor selection in 2025 and 2026
- SiPM readout mass production in 2027-2029
- dRICH detector installation in the ePIC experiment in 2030

2023 test beam data analysis ongoing

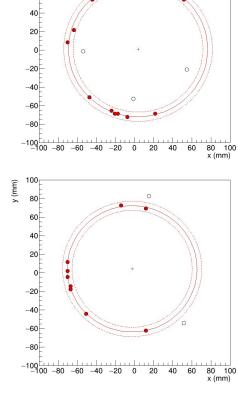
2 2 3 4 4 6

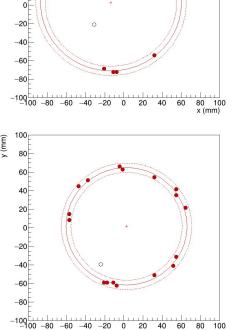
INFN

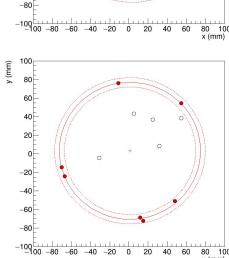


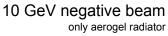
y (mm)

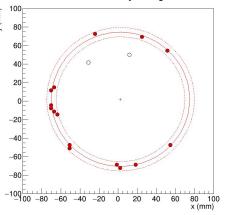
event-by-event ring reconstruction: Hough Transform Method

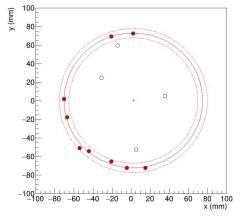




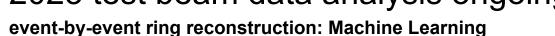






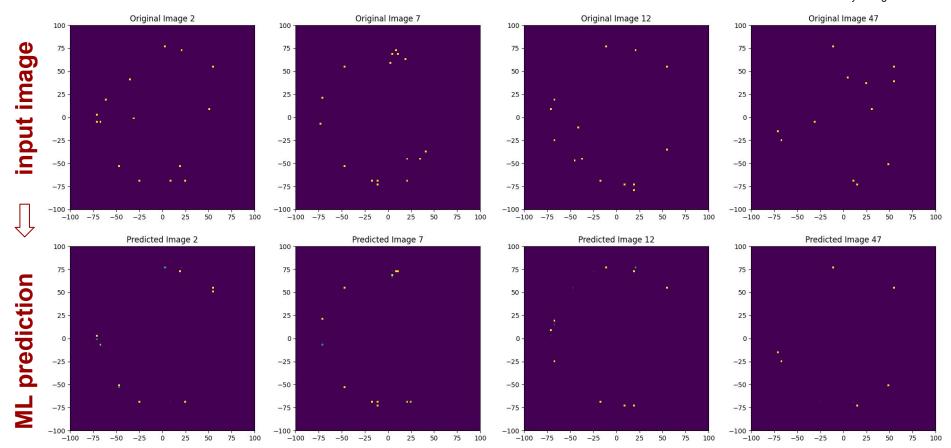


2023 test beam data analysis ongoing



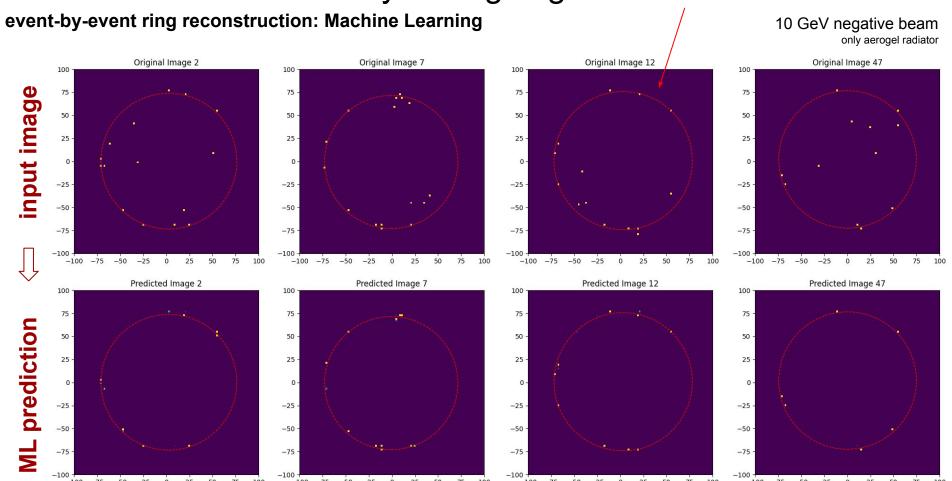






circle fit on ML prediction



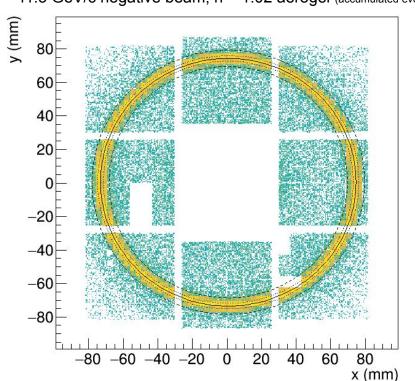


Number of photoelectrons

is large as expected



11.5 GeV/c negative beam, n = 1.02 aerogel (accumulated events)



$$X_0 = 0.75 \pm 0.01 \text{ mm}$$

$$Y_0 = 0.45 \pm 0.01 \text{ mm}$$

$$R = 73.87 \pm 0.00 \text{ mm}$$

$$\sigma_{\textrm{R}}$$
 = 1.63 \pm 0.00 mm

average number of signal photons for 100% acceptance includes SiPM efficiency

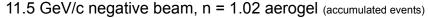
$$N_{\rm sig} = 29.13 \pm 0.07$$

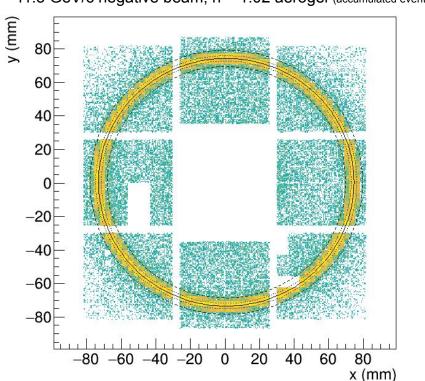
$$N_{bkg} = 8.47 \pm 0.05$$

Number of photoelectrons

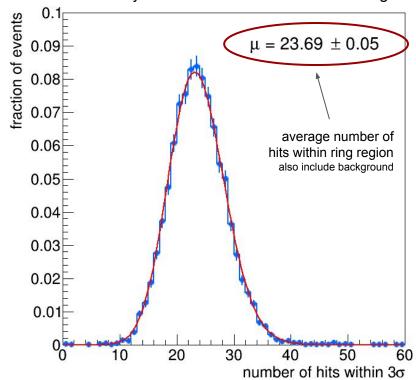
large as expected







event-by-event distribution of hits in the ring

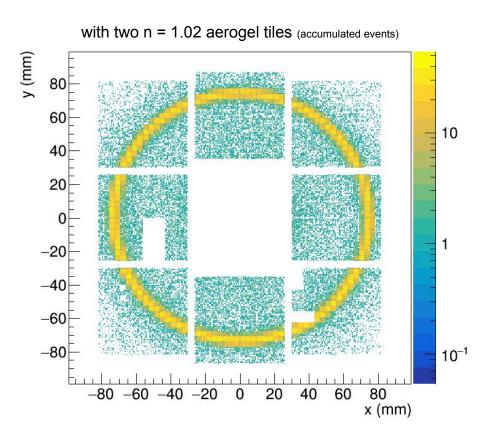


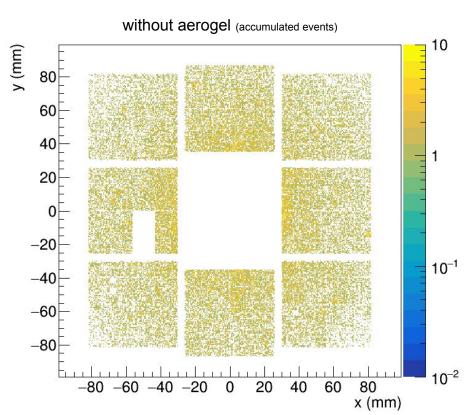
Poisson fit to data, average number of hits is large

Background studies

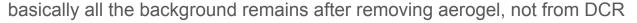
data taken without aerogel radiator



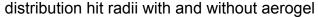


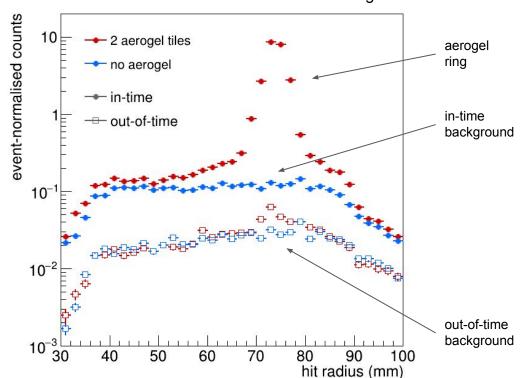


Background studies





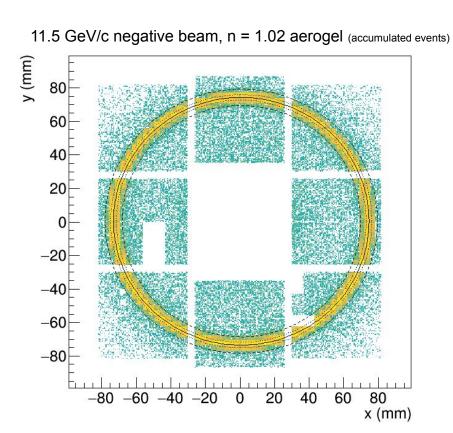


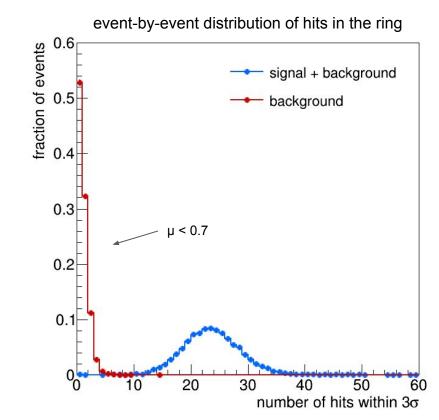


Background studies

there is often one background hit in the ring, this will impact resolution

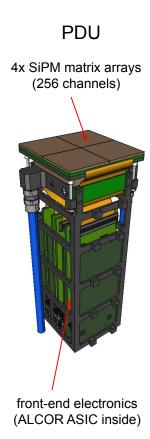


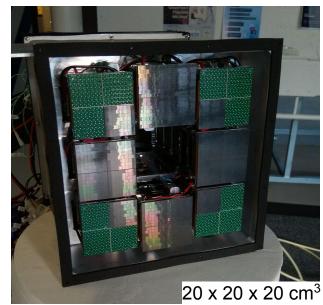




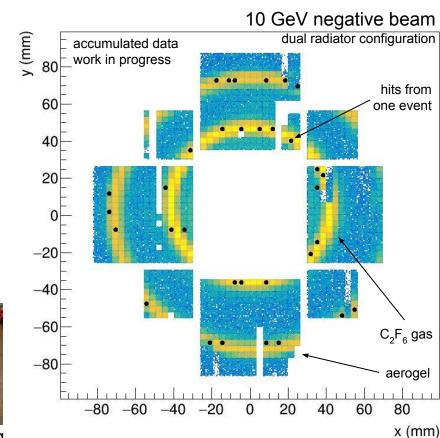


successful beam test with prototype SiPM photodetector units (CERN-PS, ended on 18th October)

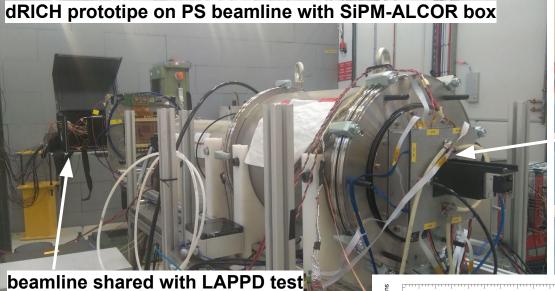






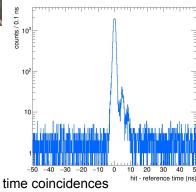


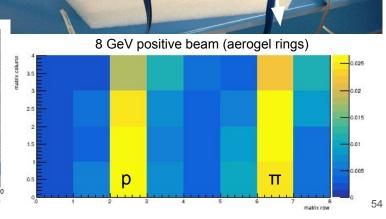




successful operation of SiPM

<u>irradiated</u> (with protons up to 10¹⁰) and <u>annealed</u> (in oven at 150 C)



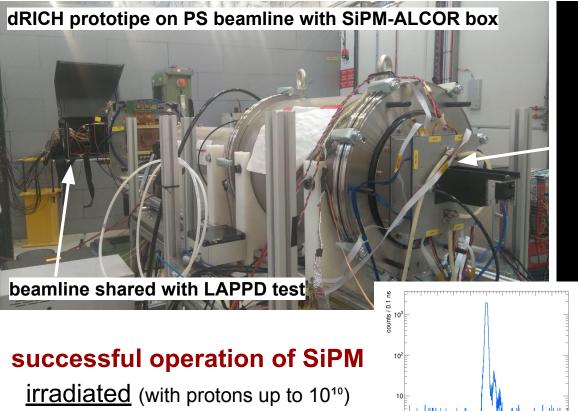


ALCOR

inside

and <u>annealed</u> (in oven at 150 C)





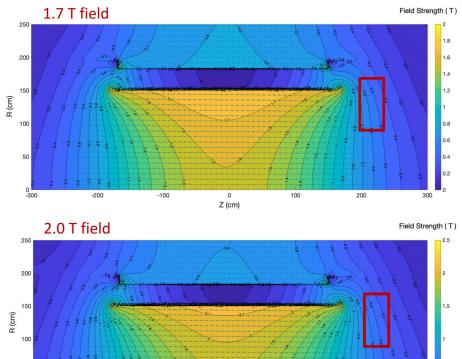
time coincidences

± 5 ns timing cut HPK 14160 **HPK 13360 SENSL FBK** 8 GeV negative beam (aerogel rings)

Environment

MARCO magnetic field maps





non-uniform, strong magnetic field ~ 0.7 T field lines ~ parallel to photodetector surface

-100

200

100

SiPM cooling for low-temperature operation (-30 °C or lower)



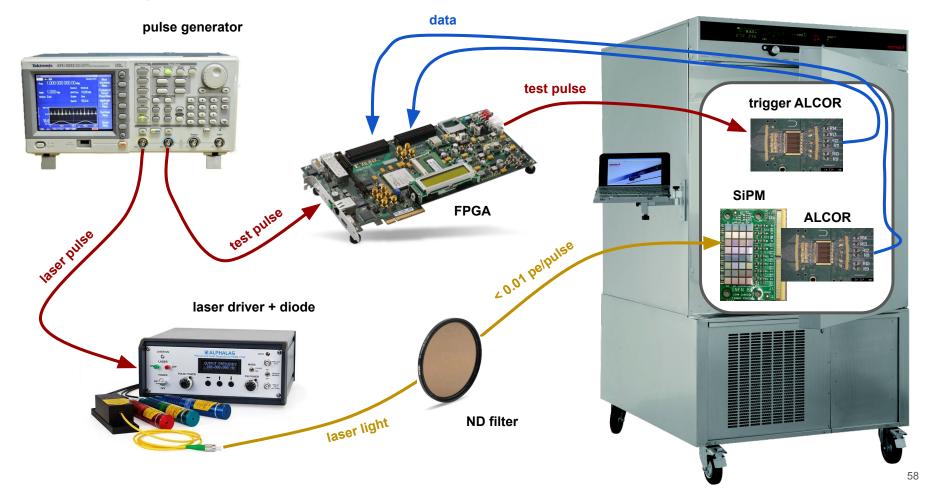


external chiller with fluid recirculation (ie. siliconic oil) the chiller here one is just a commercial example cooling and heating capacity could use heating capability for annealing? must be demonstrated to be feasible cooling capacity at -40 C is large (1.5 kW)

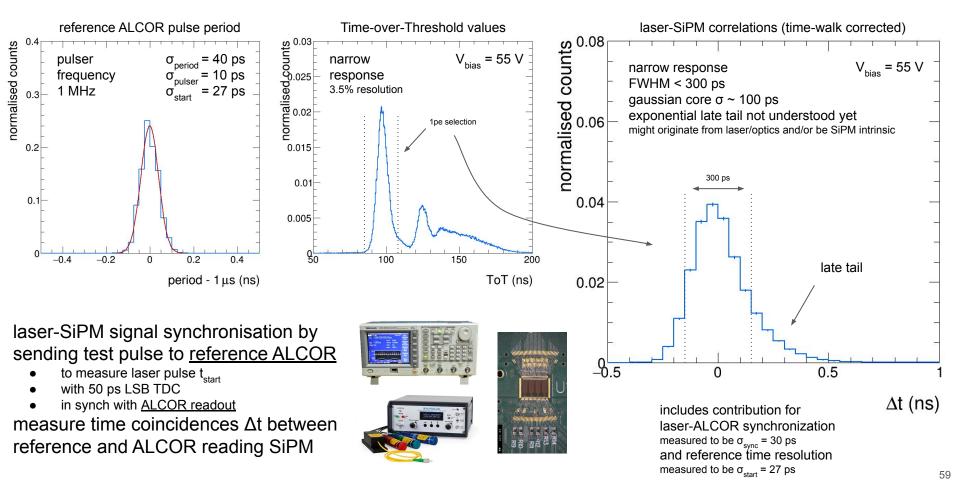


Laser timing measurements with ALCOR

climatic chamber

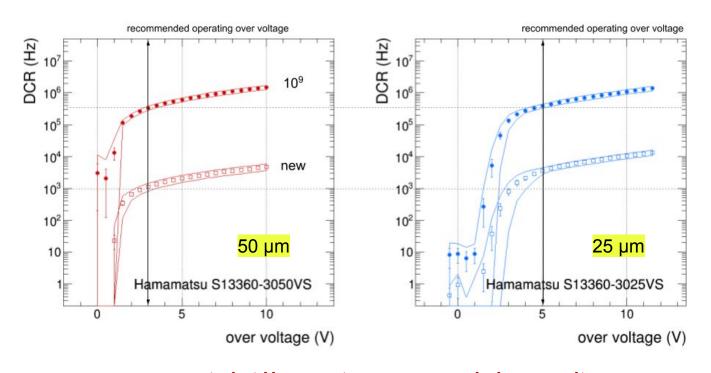


Laser timing measurements with ALCOR



Small vs. <u>large</u> SPAD sensors





sensors with small
SPADs have lower SNR
also after irradiation

small SPAD sensors are not radiation harder for single-photon applications (RICH)

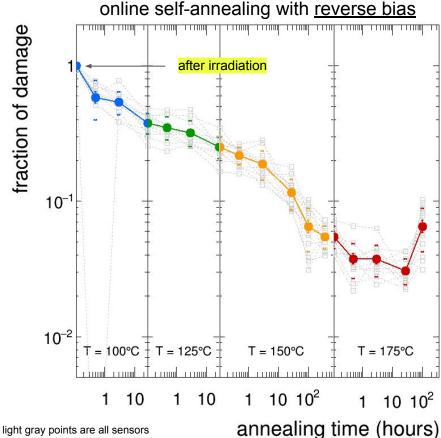
sensors operated at Hamamatsu recommended over-voltage

- [datasheet] 50 μm sensors have 40% PDE, 25 μm have 25%
- o [measured] 50 μm sensors have lower DCR than 25 μm when new
- [measured] both sensors have similar DCR after irradiation

similar results and conclusions obtained with SENSL sensors

Detailed studies of SiPM online self-annealing





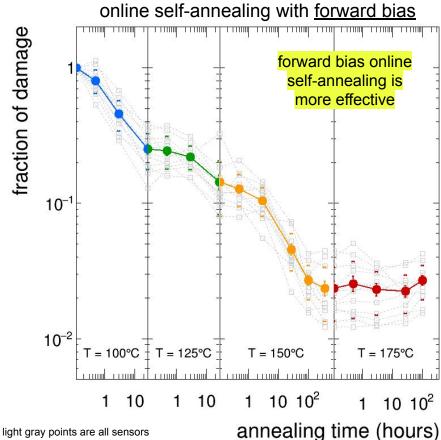
test on a large number of proton irradiated sensors how much damage is cured as a function of temperature and time

in this study, the same sensors have undergone self-annealing in increasing temperature steps and increasing integrated time steps

- started with T = 100 C annealing
 - performed 4 steps up to 30 hours integrated
- followed by T = 125, 150 and 175 C

Detailed studies of SiPM online self-annealing





test on a large number of proton irradiated sensors how much damage is cured as a function of temperature and time

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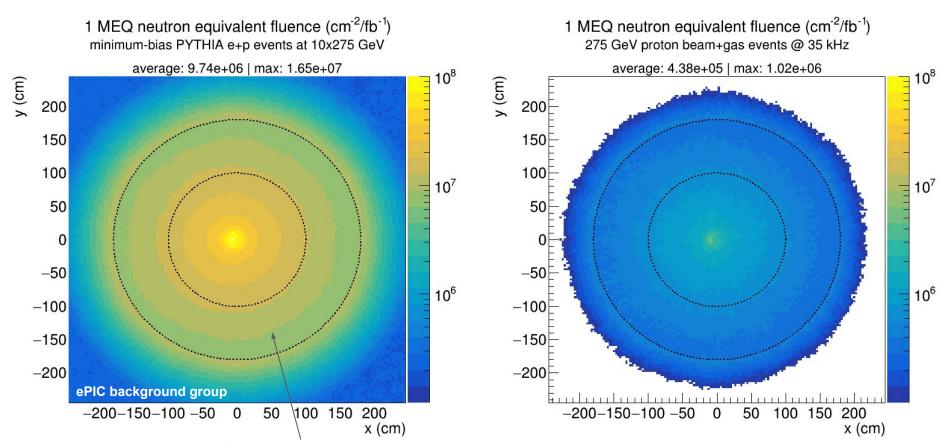
- started with T = 100 C annealing
 - performed 4 steps up to 30 hours integrated
- followed by T = 125, 150 and 175 C

fraction of residual damage seems to saturate at 2-3% after ~ 300 hours at T = 150 C

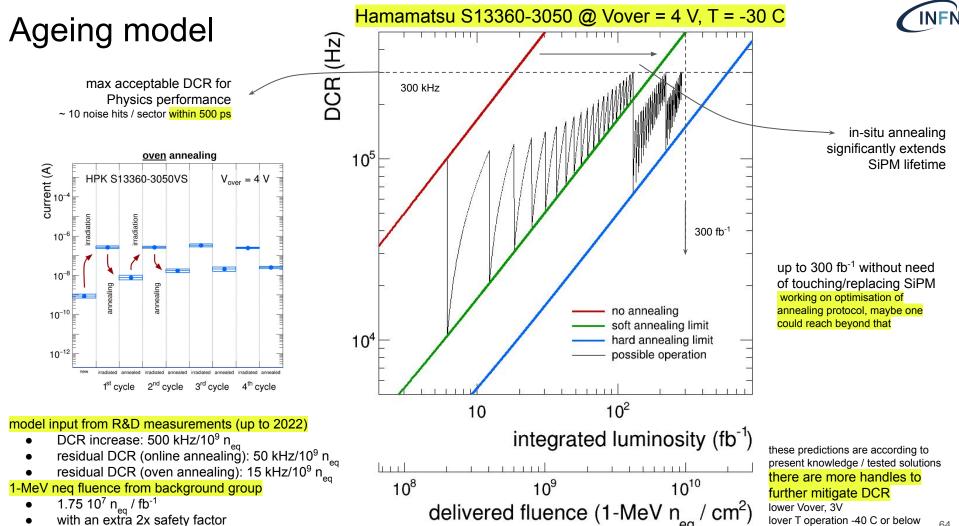
continuing at higher T = 175 C seems not to cure more than that

Radiation damage estimates





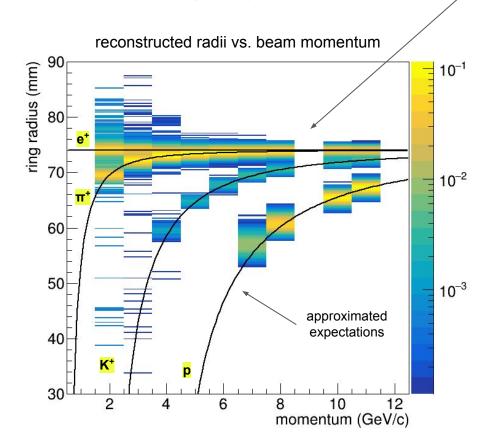
max fluence = $1.75 ext{ } 10^7 ext{ } \text{neq/fb}^{-1}$ at the location of dRICH photosensors



Beam momentum scan



positive particles, aerogel only



something went wrong with the beam configuration for 9 GeV (that's a pity, data seems not good)

reconstructed ring radius at 10 GeV/c beam momentum

